

# <2GHz Amplified Photodetectors

EOT's <2GHz Amplified Photodetectors contain PIN photodiodes that utilize the photovoltaic effect to convert optical power into an electrical current and a fixed gain transimpedance amplifier allowing measurement of <1mW input powers. When terminated into  $50\Omega$  into an oscilloscope, the pulsewidth of a laser can be measured. When terminated into  $50\Omega$  into a spectrum analyzer, the frequency response of a laser can be measured. EOT's <2GHz Amplified Photodetectors come with their own wall plug-in power supply. Plugging a coaxial cable into the photodetector's BNC output connector and terminating into  $50\Omega$  at the oscilloscope or spectrum analyzer is all that is required for operation.







### **Applications:**

- Monitoring high repetition rate, externally modulated CW lasers
- Viewing <1mW laser powers</li>

#### **Features:**

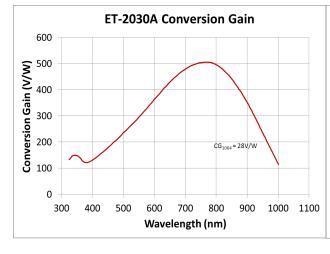
Built-in transimpedance amplifier

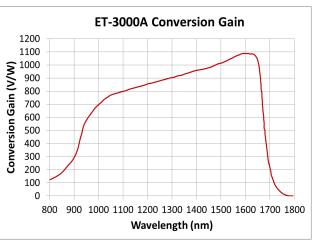
### Specifications<sup>a,b</sup>:

Detector Material   Silicon   InGaAs     Rise Time/Fall Time   <500ps/<500ps	<del>-</del>		
Detector Material   Silicon   InGaAs     Rise Time/Fall Time   <500ps/<500ps	Part No. (Model)	120-10013-0001	120-10036-0001
Rise Time/Fall Time   <500ps/<500ps   <400ps/<400ps     Conversion Gain   450V/W at 830nm   900V/W at 1300nm     Power Supply   24VDC   24VDC     Bandwidth   30kHz—1.2GHz   30kHz—1.5GHz     Active Area Diameter   400μm   100μm     Acceptance Angle (1/2 angle)   10°   20°     Noise Equivalent Power   <60pW/√Hz   <30pW/√Hz     Maximum Linear Rating   1.3V peak   1.3V peak     Mounting (Tapped Holes)   8-32 or M4   8-32 or M4		(ET-2030A)	(ET-3000A)
Conversion Gain   450V/W at 830nm   900V/W at 1300nm     Power Supply   24VDC   24VDC     Bandwidth   30kHz—1.2GHz   30kHz—1.5GHz     Active Area Diameter   400μm   100μm     Acceptance Angle (1/2 angle)   10°   20°     Noise Equivalent Power   <60pW/√Hz   <30pW/√Hz     Maximum Linear Rating   1.3V peak   1.3V peak     Mounting (Tapped Holes)   8-32 or M4   8-32 or M4	Detector Material	Silicon	InGaAs
Power Supply   24VDC   24VDC     Bandwidth   30kHz—1.2GHz   30kHz—1.5GHz     Active Area Diameter   400μm   100μm     Acceptance Angle (1/2 angle)   10°   20°     Noise Equivalent Power   <60pW/√Hz	Rise Time/Fall Time	<500ps/<500ps	<400ps/<400ps
Bandwidth   30kHz—1.2GHz   30kHz—1.5GHz     Active Area Diameter   400μm   100μm     Acceptance Angle (1/2 angle)   10°   20°     Noise Equivalent Power   <60pW/√Hz   <30pW/√Hz     Maximum Linear Rating   1.3V peak   1.3V peak     Mounting (Tapped Holes)   8–32 or M4   8–32 or M4	Conversion Gain	450V/W at 830nm	900V/W at 1300nm
Active Area Diameter 400μm 100μm   Acceptance Angle (1/2 angle) 10° 20°   Noise Equivalent Power <60pW/√Hz <30pW/√Hz   Maximum Linear Rating 1.3V peak 1.3V peak   Mounting (Tapped Holes) 8-32 or M4 8-32 or M4	Power Supply	24VDC	24VDC
Acceptance Angle (1/2 angle) 10° 20°   Noise Equivalent Power <60pW/√Hz	Bandwidth	30kHz—1.2GHz	30kHz—1.5GHz
Noise Equivalent Power   <60pW/√Hz   <30pW/√Hz     Maximum Linear Rating   1.3V peak   1.3V peak     Mounting (Tapped Holes)   8-32 or M4   8-32 or M4	Active Area Diameter	400μm	100μm
Maximum Linear Rating   1.3V peak   1.3V peak     Mounting (Tapped Holes)   8-32 or M4   8-32 or M4	Acceptance Angle (1/2 angle)	10°	20°
Mounting (Tapped Holes) 8–32 or M4 8–32 or M4	Noise Equivalent Power	<60pW/√Hz	<30pW/√Hz
	Maximum Linear Rating	1.3V peak	1.3V peak
Output Connector RNC RNC	Mounting (Tapped Holes)	8-32 or M4	8-32 or M4
DIVC	Output Connector	BNC	BNC

<sup>&</sup>lt;sup>a</sup> Product specifications are subject to change.

Note: RoHS compliant with exception.

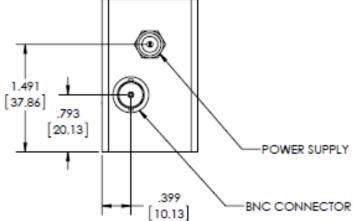




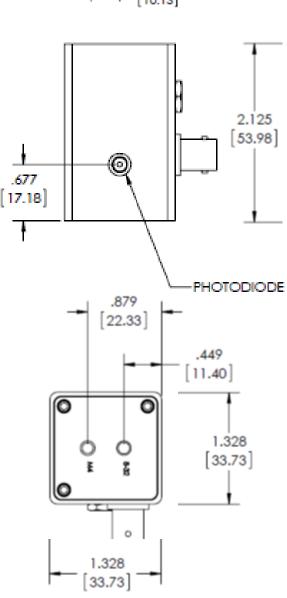
<sup>&</sup>lt;sup>b</sup> Not suitable for CW applications



## ET-2030A, 3000A Dimensions<sup>a</sup>:







<sup>&</sup>lt;sup>a</sup> All dimensions in inches